Influence of Mn doping on structural, optical, and magnetic properties of BiFeO$_3$ films fabricated by the sol-gel method

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ABSTRACT: The present study synthesized BiFe$_{1-x}$Mn$_x$O$_3$ ($x = 0.00, 0.03, 0.05$ and $0.07$) films by the sol-gel method. Rhombohedral lattice structure and phase transition are confirmed by X-ray diffraction and Raman spectroscopy. Scanning electron microscopy and atomic force microscopy images showed that with the increase of Mn content, the grain size and average roughness of the film first decreased and then increased. The saturated magnetization of the BiFe$_{1-x}$Mn$_x$O$_3$ ($x = 0.03, 0.05$ and $0.07$) films was significantly enhanced compared with the BiFeO$_3$ film, thus indicating its potential applicability for information storage. Meanwhile, the Mn-doped films exhibited a reduced optical band gap. The results verify the applicability of the presented method in improving the performance of high-efficient photocatalysis.

KEYWORDS: sol-gel method, magnetic properties, optical properties, Mn doping, BiFeO$_3$ films

INTRODUCTION

Multiferroics are multifunctional materials that simultaneously possess two or more ferroic orders such as ferroelectric and ferromagnetic [1]. With the continuous development of science and technology, multiferroic materials have been widely used in electronic devices and in various smart devices such as spintrons, magnetoelectric memory and piezotronics [2]. Room-temperature multiferroic Bismuth Ferrite BiFeO$_3$ (BFO) is a rhombohedral distorted ferroelectric perovskite with space group R3c below the Curie temperature ($T_C \approx 1100$ K) and shows antiferromagnetic behavior below the Néel temperature ($T_N \approx 643$ K) [3]. However, the special magnetic cycloidal spiral arrangement for Fe$^{3+}$, which has a long cycle length of 60–64 nm [4] and results in nearly zero macroscopic magnetization [5, 6], generated the performance of bulk BFO for the technological applications is not satisfied for magnetic requirements. Moreover, in recent years, researchers have found that BFO not only has a small optical band gap (2.2–2.9 eV) but also possesses favorable nonlinear optical properties, thus widening the application of BFO [7]. Therefore, further examination of the optical, magnetic and structural properties of BFO films to improve its performance is worthwhile [8].

Various methods have been used for the preparation of BFO films, including of magnetron sputtering [9], hydrothermal method [10] and sol-gel method [11]. However, the sol-gel method is one of the simpler methods used in the preparation of thin films due to its straightforward composition control, large area coatings and inexpensive equipment costs. The preparation of BFO films with the sol-gel method focuses on properties improvement via rare-earth and transition metals substitution at the A- and B-sites, respectively [12, 13]. Doping of various Lanthanide ions (Gd$^{3+}$) [14], Sm$^{3+}$ [3] and Nd$^{3+}$ [15] at the Bi$^{3+}$ site of BFO has been reported to improve the magnetic and ferroelectric properties via suppression of the spiral spin structure and reduction of oxygen vacancies. Meanwhile, B-site ordering of the transition-metal ions has exhibited the ability to generate ferromagnetic or ferrimagnetic BFO materials. Similarly, doping of the transition metal ions Zn$^{2+}$ [16], Mn$^{2+}$ [8], Ni$^{2+}$ [5] and Mg$^{2+}$ [17] at the Fe$^{3+}$ site of BFO has also enhanced its magnetic and ferroelectric properties [18]. The replacement of ions at the A site at different ionic radii can readjust the structure to reduce the leakage current, as well as increase polarization [19]. Furthermore, substitution at the A site can increase the magnetism by releasing suppressed spiral spin...
modulation of the G-type antiferromagnetism [20]. Although, intensive research works have reported the ferro-electric and magnetic properties of BFO films by adjusting the Mn doping concentration, the optical properties and surface roughness morphologies require further investigation. The present work first grew BiFe$_{1-x}$Mn$_x$O$_3$ ($x = 0.00, 0.03, 0.05$ and $0.07$) films on SiO$_2$/Si substrates by the sol-gel method. Then, structures, surface morphologies, and optical and magnetic properties of the samples were investigated. In particular, the optical properties of the BFMO films were studied based on their absorption spectra.

**MATERIALS AND METHODS**

Pure BFO and transition metal Mn-doped BFO films were prepared by the sol-gel method. Bismuth (III) nitrate pentahydrate [Bi(NO$_3$)$_3$·5 H$_2$O] (5% excess to compensate for the loss of Bi due to evaporation during the post-annealing process), Ferric (III) nitrate nonahydrate [Fe(NO$_3$)$_3$·9 H$_2$O] and Manganese acetate [C$_{4}$H$_{9}$MnO$_4$(Mn(CH$_3$COO)$_2$) were used as the raw materials. Ethylene glycol methyl ether and glacial acetic acid were used as solvents. Twenty milliliters of a 0.325 mol $\cdot$ L$^{-1}$ solution of every doping amount were then prepared. Then, the solution was magnetically stirred for 3 h and kept at room temperature for 24 h. In this work, the SiO$_2$/Si substrate was sequentially cleaned with acetone, ethanol, and deionized water for 5 min. Furthermore, the precursor solution was spin-coated on the SiO$_2$/Si substrate at a spinning speed of 4000 rpm for 20 s. Subsequently, the spin-coated wet film was preheated on a hot plate at 200 °C for 5 min. The coating process was repeated 15 times. Finally, the obtained film was annealed in air at a temperature of 550 °C for 10 min.

The BiFe$_{1-x}$Mn$_x$O$_3$ (BFMO) film crystal structures and phase purity were identified by X-ray diffractometry (XRD, Bruker D2, D8 Advance, Germany) with CuKα rays at a wavelength of 1.5418 Å, and within an XRD profile range of 20°–60°. The surface morphologies of the BFMO films were characterized by scanning electron microscopy (SEM, SU8010, HITACHI, Japan) and atomic force microscopy (AFM, Dimension Icon, Germany), respectively. Raman spectra of samples were measured via Raman spectrometry (AES, iHR550, Horiba, France). The optical properties of the BFMO films were measured by UV-visible spectrophotometry (UV-vis, UV/vis Lambda 650, Perkin Elmer Company, Waltham, Massachusetts, USA). The magnetization of the samples were measured by vibrat-

![Fig. 1](image)

**RESULTS AND DISCUSSION**

Fig. 1 shows the XRD spectra of the BiFe$_{1-x}$Mn$_x$O$_3$ ($x = 0.00, 0.03, 0.05$ and $0.07$) films grown on the SiO$_2$/Si substrates. All of the peaks in the XRD spectra corresponded to a perovskite-type rhombohedral structure (PDF72-2321) that belonged to the R3c (160) space group. The XRD patterns confirm the presence of strong crystal plane in the (012), (104), (110), (111), (024), (116), (122), (214) and (300) directions, which fit into the main peaks of the BiFe$_{1-x}$Mn$_x$O$_3$ films. An increase in Mn doping increased the intensity of the diffraction peaks, indicating that Mn doping promoted crystallinity. For each sample, the average grain size was estimated...
using the Scherrer formula [21]. Doping contents of \(x = 0.00, 0.03\) and 0.05 generated film grain sizes of 32.6 nm, 19.7 nm and 19.5 nm, respectively, indicating a contrasting trend between the grain size and doping content. A Mn doping amount of \(x = 0.07\) exhibited an increase in the BFMO film grain size to 45 nm, suggesting that the grain size first decreased and then increased with the Mn doping amount, which agrees with a previous report [20].

According to Fig. 1(b), all of the peak positions of the BFMO films slightly shifted towards the right following an increase in the Mn concentration compared with BFO, which can be attributed to a small distortion in the crystal structure due to the smaller ionic radius of the Mn\(^{2+}\) ions (0.067 nm) partially substitute by the Fe\(^{3+}\) ions (0.087 nm). This result is in accordance with previous reports [22]. Moreover, the presence of impurity, such as Fe\(_2\)O\(_3\), could be assigned to the high temperature that accelerated the volatilization of the Bi elements and reduced the content of Bi\(_2\)O\(_3\), which resulted in an enriched Fe\(_2\)O\(_3\) impurity phase [18].

Fig. 2 presents the surface morphologies of pure BFO and the BFMO films, which were measured by SEM. All of the samples exhibited good crystallinity. The average grain size of the samples first decreased and then increased with the increasing Mn content. Both the BFO and BFMO films \((x = 0.07)\) exhibited well-crystallized microstructures and smooth surfaces. The BFMO films \((x = 0.03\) and 0.05) showed a gradually decreasing grain size and inhomogeneous surface micrographs. In this case, the crystal grains exhibited an irregular polyhedron. Additionally, more defects were formed at the grain boundaries, resulting in a decrease in the grain size.

The surface topography and roughness of the BFMO films were characterized by AFM (Fig. 3). The average roughness \((R_a)\) of the films was measured over an area of 2.5 \(\mu m \times 2.5 \mu m\), of which the BFMO films exhibited \(R_a\) values of 6.35 nm, 2.74 nm, 2.19 nm and 6.58 nm at Mn contents of \(x = 0.0, 0.03, 0.05\) and 0.07, respectively. The \(R_a\) of the samples first decreased and then increased with the increasing Mn content. The AFM results indicated that Mn doping strongly affected the roughness of the BFMO films, which agrees well with the XRD spectra [23, 24].

Fig. 4(a) shows the Raman spectrum of pure BFO. Four A\(_1\) modes at Raman shifts of 145, 180, 199 and 247 cm\(^{-1}\) were observed in the Raman spectra of pure BFO. The Raman spectra of the BFMO films showed a similar pattern but with a slight shift in the peaks due to the substitution of Mn ions. The peak at 145 cm\(^{-1}\) was assigned to the A\(_1\) mode of the BFO lattice, while the peak at 180 cm\(^{-1}\) was attributed to the vibration of the Bi-O bond. The peaks at 199 and 247 cm\(^{-1}\) were assigned to the Fe-O bond vibration.

Fig. 2 SEM images of BiFe\(_{1-x}\)Mn\(_x\)O\(_3\) films, where (a), (b), (c) and (d) are corresponding to \(x = 0.00, 0.03, 0.05\) and 0.07, respectively.
225 and 470 cm\(^{-1}\) and eight E-1 mode peaks at 82, 266, 285, 307, 354, 376, 549 and 619 cm\(^{-1}\) confirmed the structure of the BFO films [25]. However, only 12 active modes were observed, indicating the absence of one active mode (E-7). The absence of this particular Raman peak may be due to the higher local stress and the presence of point defects in the pure BFO sample [26]. However, the peak intensity increased and peaks slightly red shifted compared with pure BFO. The low-wave number Raman modes were governed by Bi–O vibration, and the high-wave number Raman modes were related to the Fe–O vibration [14, 25]. The intensity of \(A_1\) mode increased with the Mn dopant, suggesting the chemical activity enhancement of the Bi–O isolation electron, which may be due to the local lattice distortion in the as-prepared samples [20]. In addition, certain Raman peaks exhibited changes in their relative widths, possibly due to the structure transition of the BFO lattice [22]. These results were also in accordance with the XRD results. Moreover, the insert in Fig. 4(b) presents the Raman peak of the \([A_1-1]\) mode at 145 cm\(^{-1}\), which was red-shifted with the increasing Mn substitution. This result can be attributed to the lower atomic weight of Mn (54.9 g/mol) compared with Fe (55.8 g/mol), since the frequency of the Raman modes was dependent on the force constant and ionic mass [27].

The magnetic hysteresis \((M - H)\) loops of the BFMO films are shown in Fig. 5, which clearly indicate weak ferromagnetism for all of the films. A previous report correlated the weak ferromagnetism in BFO with the rhombohedral distorted perovskite structure (space group R3c), in which both ferroelectric atomic displacements and weak ferromagnetism were allowed [28]. The inset shows the saturated magnetization \((M_s)\) as a function of the Mn content \((x)\). The \(M_s\) of the BFO \((x = 0.00, 0.03, 0.05\) and 0.07\) films were approximately 0.036, 0.061, 0.064 and 0.085 emu/g, respectively, per total sample mass. The enhancement of magnetic properties attributed to the increase of Mn content, inducing more structural distortions, thus suppressing cycloid spin structure in the BFMO films [24], which coincides with the XRD results. According to Fig. 1(b), the increase in the Mn content shifted all of the peak positions towards the larger angle direction, thus revealing a more structural distortion.

Fig. 6 shows the absorption spectra in the wavelength range from 300–700 nm of BFMO films. All of the samples exhibited strong light absorption in
both the UV and visible light regions (Fig. 6(a)), demonstrating that the as-prepared BFO could respond to visible light for the photocatalytic reaction. Compared to the BFO, the BFMO samples showed improved absorption in the visible light region, especially for the $x = 0.07$ sample. The optical absorbance properties were relevant to the electronic structure features and band gaps [29]. The optical band gaps ($E_g$) of the BFMO samples were determined by Tauc’s law [30]. The BFMO films exhibited $E_g$ values of 2.28 eV, 2.24 eV, 2.27 eV and 2.20 eV at Mn contents of $x = 0.00$, 0.03, 0.05 and 0.07, respectively (Fig. 6(b)). The $E_g$ values clearly decreased with the Mn dopant possibly due to the energy levels of the doping ions entering the band gap and transitioning to impurity levels as the doping amount further increased, and resulting in narrow band gaps. Thus, the substitution of Mn ions in the BFO film Fe sites resulted in decreased $E_g$ values [31]. Smaller BFMO film $E_g$ values resulted in wider visible light regions for the photovoltaic devices.

In summary, BiFe$_{1-x}$Mn$_x$O$_3$ ($x = 0.00$, 0.03, 0.05 and 0.07) films were synthesized by the sol-gel method. The XRD analysis revealed effectiveness of Mn doping in enhancing the film crystallinity. In particular, as the amount of doping increased, the grain size first decreased and then increased. The AFM images showed that the roughness of the BFMO film depended on the doping content. Meanwhile, the saturated magnetization of the BFMO films increased with the Mn content, which indicates the promising effectiveness of the BFMO film as a candidate for multiferroic device applications. The film band gap decreased from 2.28 eV to 2.20 eV, suggesting that the smaller band gap of the BFMO film resulted in a wider visible light region for photovoltaic devices.

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